onsemi

Self-Protected Low Side Driver with Temperature and Current Limit

42 V, 14 A, Single N-Channel

NCV8403A, NCV8403B

NCV8403A/B is a three terminal protected Low-Side Smart Discrete device. The protection features include overcurrent, overtemperature, ESD and integrated Drain-to-Gate clamping for overvoltage protection. This device offers protection and is suitable for harsh automotive environments.

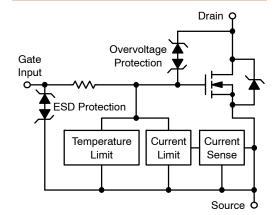
Features

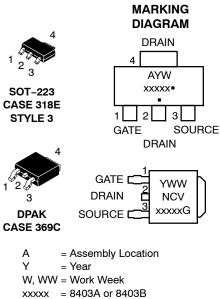
- Short Circuit Protection
- Thermal Shutdown with Automatic Restart
- Over Voltage Protection
- Integrated Clamp for Inductive Switching
- ESD Protection
- dV/dt Robustness
- Analog Drive Capability (Logic Level Input)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Switch a Variety of Resistive, Inductive and Capacitive Loads
- Can Replace Electromechanical Relays and Discrete Circuits
- Automotive / Industrial

| V _{DSS} (Clamped) | R _{DS(on)} TYP | I _D MAX (Limited) |
|-------------------------------|-------------------------|---------------------------------|
| 42 V | 53 mΩ @ 10 V | 15 A |





G or = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information page 10 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 10.

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

| Rating | Symbol | Value | Unit |
|---|--|------------------------------------|--------|
| Drain-to-Source Voltage Internally Clamped | V _{DSS} | 42 | Vdc |
| Gate-to-Source Voltage | V _{GS} | ±14 | Vdc |
| Drain Current Continuous | I _D | Internally L | imited |
| Total Power Dissipation - SOT-223 Version(@ $T_A = 25^{\circ}C$ (Note 1)(@ $T_A = 25^{\circ}C$ (Note 2)Total Power Dissipation - DPAK Version(@ $T_A = 25^{\circ}C$ (Note 1)(@ $T_A = 25^{\circ}C$ (Note 2) | P _D | 1.13 1.56 1.32 2.5 | W |
| Thermal Resistance – SOT-223 Version Junction-to-Soldering Point Junction-to-Ambient (Note 1) Junction-to-Ambient (Note 2) Thermal Resistance – DPAK Version Junction-to-Soldering Point Junction-to-Ambient (Note 1) Junction-to-Ambient (Note 2) | $\begin{array}{c} R_{\theta JS} \\ R_{\theta JA} \\ R_{\theta JA} \\ R_{\theta JS} \\ R_{\theta JA} \\ R_{\theta JA} \\ R_{\theta JA} \end{array}$ | 12 110 80 2.5 95 50 | °C/W |
| Single Pulse Inductive Load Switching Energy (V _{DD} = 25 Vdc, V _{GS} = 5.0 V, I _L = 2.8 A, L = 120 mH, R _G = 25 Ω) | E _{AS} | 470 | mJ |
| Load Dump Voltage (V_{GS} = 0 and 10 V, R_I = 2.0 $\Omega,$ R_L = 4.5 $\Omega,$ t_d = 400 ms) | V _{LD} | 55 | V |
| Operating Junction Temperature | TJ | -40 to 150 | °C |
| Storage Temperature | T _{stg} | –55 to 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Surface mounted onto minimum pad size (0.412" square) FR4 PCB, 1 oz cu.
Mounted onto 1" square pad size (1.127" square) FR4 PCB, 1 oz cu.

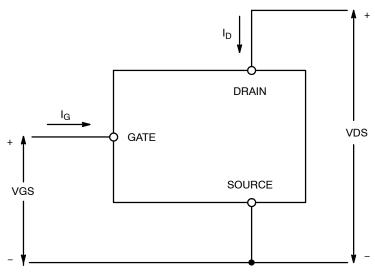


Figure 1. Voltage and Current Convention

| Characte | Symbol | Min | Тур | Max | Unit | |
|---|---|-------------------------------------|------------|------------|------------|--------------|
| OFF CHARACTERISTICS | | - | - | - | - | |
| $\begin{array}{l} \text{Drain-to-Source Clamped Breakdown Vol}\\ (V_{GS}=0 \ Vdc, \ I_D=250 \ \mu Adc)\\ (V_{GS}=0 \ Vdc, \ I_D=250 \ \mu Adc, \ T_J=-40) \end{array}$ | V _{(BR)DSS} | 42 40 | 46 45 | 51 51 | Vdc Vdc | |
| Zero Gate Voltage Drain Current ($V_{DS} = 32$ Vdc, $V_{GS} = 0$ Vdc) ($V_{DS} = 32$ Vdc, $V_{GS} = 0$ Vdc, $T_J = 150^{\circ}$ | I _{DSS} | | 0.6 2.5 | 5.0 - | μAdc | |
| Gate Input Current (V _{GS} = 5.0 Vdc, V _{DS} = 0 Vdc) | | I _{GSS} | - | 50 | 125 | μAdc |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 1.2 \text{ mAdc})$ Threshold Temperature Coefficient (Ne | gative) | V _{GS(th)} | 1.0 _ | 1.7 5.0 | 2.2 _ | Vdc mV/°C |
| $\begin{array}{l} \mbox{Static Drain-to-Source On-Resistance (N \\ \mbox{(V}_{GS} = 10 \mbox{ Vdc}, \mbox{I}_{D} = 3.0 \mbox{ Adc}, \mbox{T}_{J} @ 25^{\circ} \\ \mbox{(V}_{GS} = 10 \mbox{ Vdc}, \mbox{I}_{D} = 3.0 \mbox{ Adc}, \mbox{T}_{J} @ 150 \end{array}$ | R _{DS(on)} | | 53 95 | 68 123 | mΩ | |
| $\begin{array}{l} \mbox{Static Drain-to-Source On-Resistance (N \\ (V_{GS} = 5.0 \mbox{ Vdc}, I_D = 3.0 \mbox{ Adc}, T_J @ 250 \\ (V_{GS} = 5.0 \mbox{ Vdc}, I_D = 3.0 \mbox{ Adc}, T_J @ 150 \end{array}$ | R _{DS(on)} | | 63 105 | 76 135 | mΩ | |
| Source–Drain Forward On Voltage (I _S = 7.0 A, V _{GS} = 0 V) | V _{SD} | _ | 0.95 | 1.1 | V | |
| SWITCHING CHARACTERISTICS (Note 3 | 3) | | | | | |
| Turn–ON Time (10% V _{IN} to 90% I _D) | $V_{IN} = 0 V$ to 5 V, $V_{DD} = 25 V$ | t _{ON} | | 44 | | μs |
| Turn–OFF Time (90% V_{IN} to 10% I_D) | $I_{\rm D} = 1.0$ A, Ext $R_{\rm G} = 2.5 \Omega$ | t _{OFF} | | 84 | | - |
| Turn–ON Time (10% V _{IN} to 90% I _D) | V _{IN} = 0 V to 10 V, V _{DD} = 25 V | t _{ON} | | 15 | | |
| Turn–OFF Time (90% V_{IN} to 10% I_D) | I_D = 1.0 A, Ext R _G = 2.5 Ω | t _{OFF} | | 116 | | |
| Slew-Rate ON (20% V_{DS} to 50% $V_{DS})$ | V _{in} = 0 to 10 V, V _{DD} = 12 V, | -dV _{DS} /dt _{ON} | | 2.43 | | V/μs |
| Slew-Rate OFF (80% V_{DS} to 50% $V_{DS})$ | | | | 0.83 | | |
| SELF PROTECTION CHARACTERISTICS | $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ (N | ote 5) | | | | |
| Current Limit | $\label{eq:VGS} \begin{array}{l} V_{GS} = 5.0 \ \text{V}, \ V_{DS} = 10 \ \text{V} \\ V_{GS} = 5.0 \ \text{V}, \ T_J = 150^\circ \text{C} \ (\text{Notes } 3, \ 6) \end{array}$ | I _{LIM} | 10 5.0 | 15 10 | 20 15 | Adc |
| Current Limit | V_{GS} = 10 V, V_{DS} = 10 V V_{GS} = 10 V, T_J = 150°C (Notes 3, 6) | I _{LIM} | 12 8.0 | 17 13 | 22 18 | Adc |
| Temperature Limit (Turn-off) | V _{GS} = 5.0 Vdc (Notes 3, 6) | T _{LIM(off)} | 150 | 175 | 200 | °C |
| Thermal Hysteresis | $V_{GS} = 5.0 \text{ Vdc}$ | $\Delta T_{LIM(on)}$ | - | 15 | - | °C |
| Temperature Limit (Turn-off) | V _{GS} = 10 Vdc (Notes 3, 6) | T _{LIM(off)} | 150 | 165 | 185 | °C |
| Thermal Hysteresis | V _{GS} = 10 Vdc | $\Delta T_{LIM(on)}$ | _ | 15 | _ | °C |
| GATE INPUT CHARACTERISTICS (Note | 3) | | | | | |
| Device ON Gate Input Current | V _{GS} = 5 V I _D = 1.0 A | I _{GON} | | 50 | | μΑ |
| | V _{GS} = 10 V I _D = 1.0 A | | | 400 | | |
| Current Limit Gate Input Current | $V_{GS} = 5 V, V_{DS} = 10 V$ | I _{GCL} | | 0.1 | | mA |
| | V_{GS} = 10 V, V_{DS} = 10 V | | | 0.6 | | |
| Thermal Limit Fault Gate Input Current | V _{GS} = 5 V, V _{DS} = 10 V | I _{GTL} | | 0.45 | | mA |
| V _{GS} = 10 V, V _{DS} = 10 V | | | | 1.5 | | |
| ESD ELECTRICAL CHARACTERISTICS | $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ (No | te 3) | | | | |
| Electro-Static Discharge Capability | Human Body Model (HBM) | ESD | 4000 | - | - | V |
| Electro-Static Discharge Capability | Machine Model (MM) | ESD | 400 | - | - | V |
| | | | | | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Not subject to production testing.

Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.
Fault conditions are viewed as beyond the normal operating range of the part.

6. Refer to Application Note AND8202/D for dependence of protection features on gate voltage.

TYPICAL PERFORMANCE CURVES

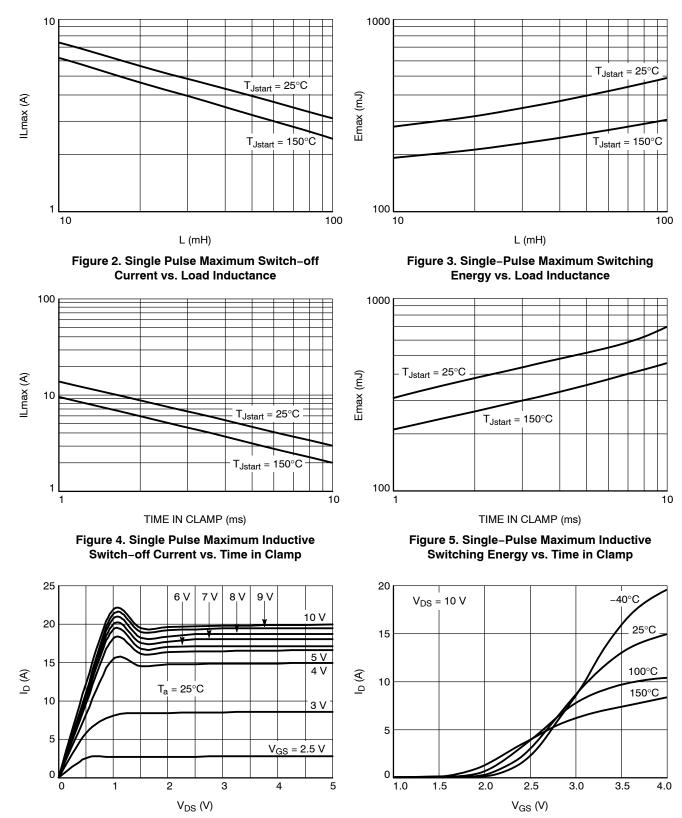
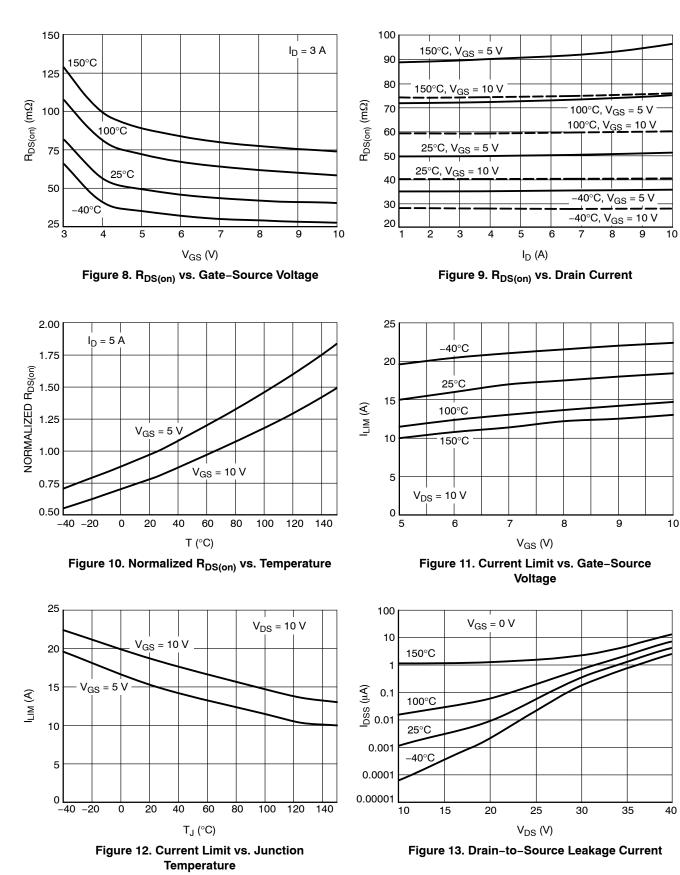


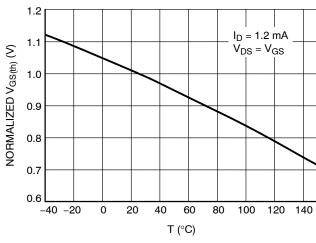
Figure 6. On-state Output Characteristics

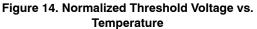
Figure 7. Transfer Characteristics

TYPICAL PERFORMANCE CURVES



TYPICAL PERFORMANCE CURVES





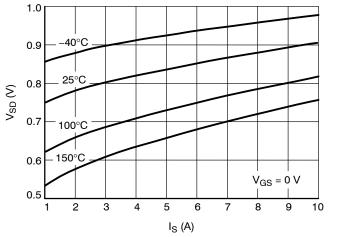
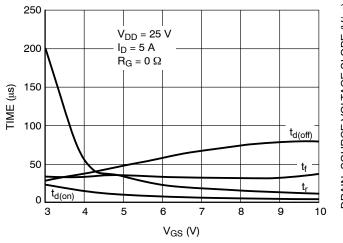
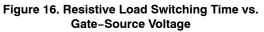


Figure 15. Source-Drain Diode Forward Characteristics





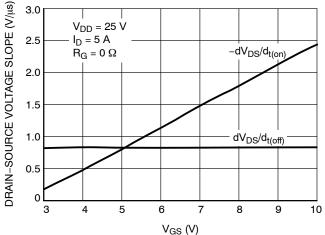
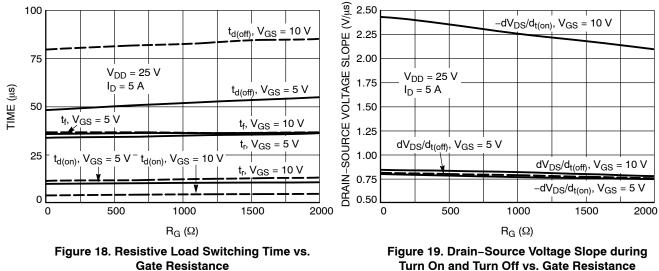
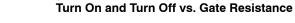
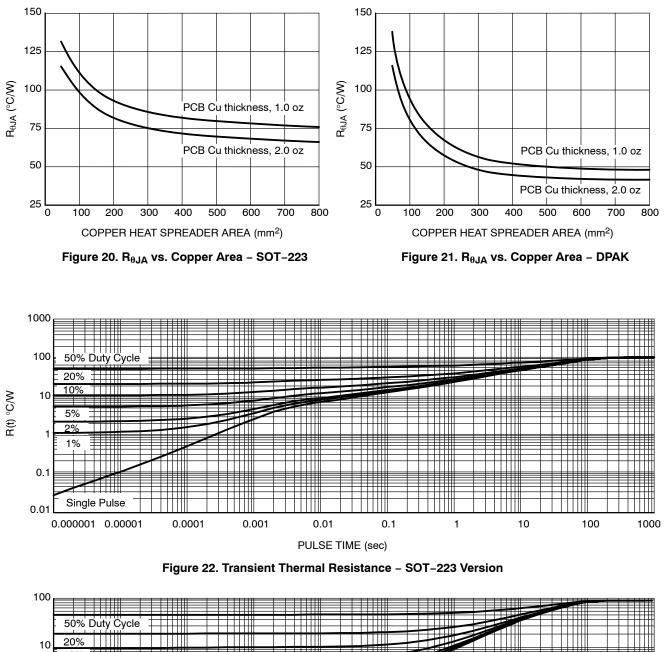


Figure 17. Resistive Load Switching Drain-Source Voltage Slope vs. Gate-Source Voltage





TYPICAL PERFORMANCE CURVES



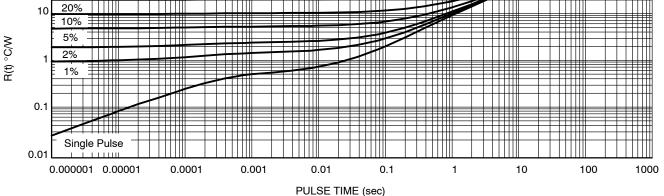


Figure 23. Transient Thermal Resistance – DPAK Version

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TEST CIRCUITS AND WAVEFORMS

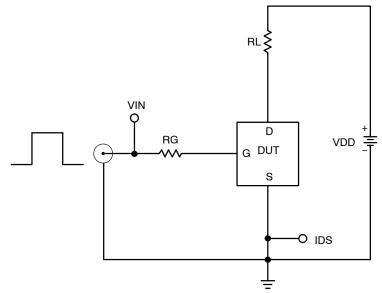


Figure 24. Resistive Load Switching Test Circuit

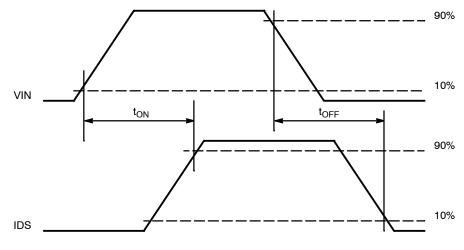


Figure 25. Resistive Load Switching Waveforms

TEST CIRCUITS AND WAVEFORMS

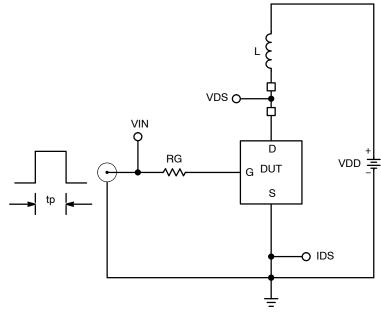
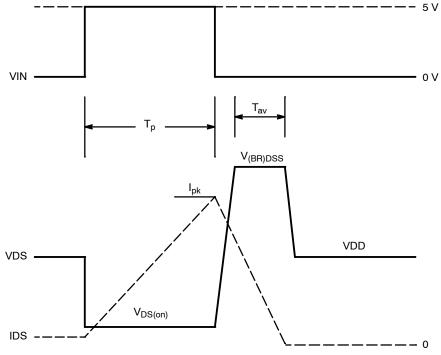


Figure 26. Inductive Load Switching Test Circuit





ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|----------------------|-----------------------|
| NCV8403ASTT1G | SOT-223 (Pb-Free) | 1000 / Tape & Reel |
| NCV8403ASTT3G | SOT-223 (Pb-Free) | 4000 / Tape & Reel |
| NCV8403BDTRKG | DPAK (Pb-Free) | 2500 / Tape & Reel |

DISCONTINUED (Note 7)

| NCV8403ADTRKG | DPAK (Pb-Free) | 2500 / Tape & Reel |
|---------------|-------------------|--------------------|

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DISCONTINUED: This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on <u>www.onsemi.com</u>.

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SEE DETAIL A

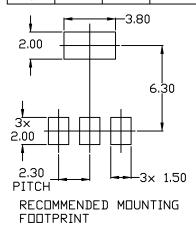
FRONT VIEW

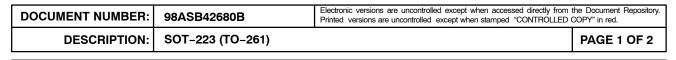
DATE 02 OCT 2018



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- AI IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS & AND &1.

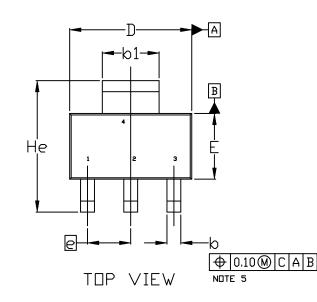
| | MILLIMETERS | | | |
|-----|-------------|------|-------------|--|
| DIM | MIN. | NDM. | MAX. | |
| A | 1.50 | 1.63 | 1.75 | |
| A1 | 0.02 | 0.06 | 0.10 | |
| b | 0.60 | 0.75 | 0.89 | |
| b1 | 2.90 | 3.06 | 3.20 | |
| с | 0.24 | 0.29 | 0.35 | |
| D | 6.30 | 6.50 | 6.70 | |
| E | 3.30 | 3.50 | 3.70 | |
| e | 2.30 BSC | | | |
| L | 0.20 | | | |
| L1 | 1.50 | 1.75 | 2.00 | |
| He | 6.70 | 7.00 | 7.30 | |
| θ | 0* | | 10 ° | |

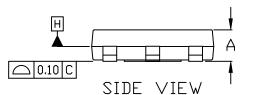


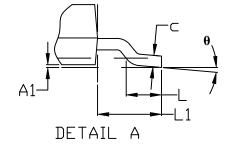


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SCALE 1:1







SOT-223 (TO-261) CASE 318E-04 ISSUE R

DATE 02 OCT 2018

| STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR | STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE | STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN | Style 4: Pin 1. Source 2. Drain 3. Gate 4. Drain | STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE |
|---|--|--|--|--|
| STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT | STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE | STYLE 8: CANCELLED | STYLE 9: Pin 1. Input 2. Ground 3. Logic 4. Ground | STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE |
| STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2 | Style 12: Pin 1. Input 2. Output 3. NC 4. Output | STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR | | |

GENERIC MARKING DIAGRAM*

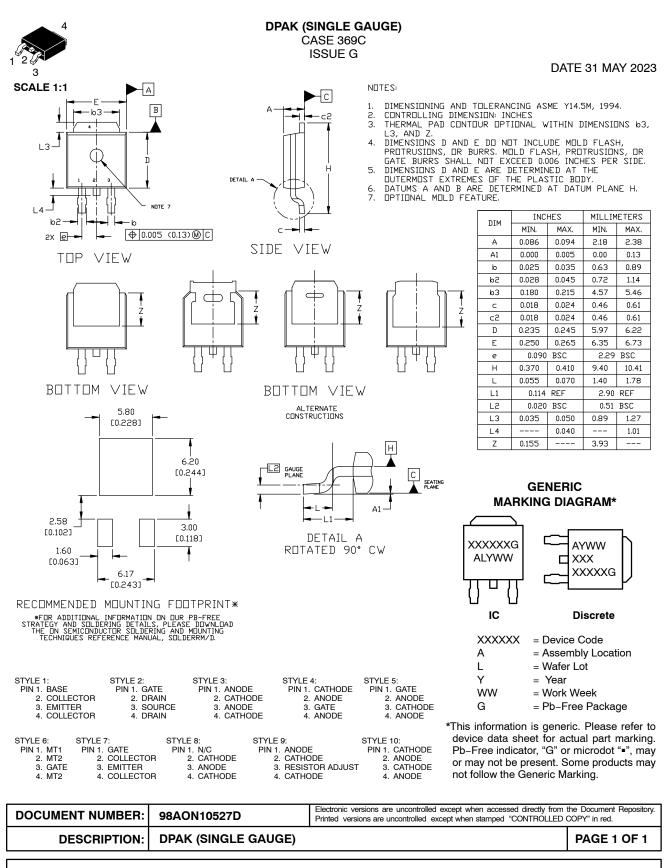


- A = Assembly Location
- Y = Year
- W = Work Week
- XXXXX = Specific Device Code
- = Pb-Free Package
- (Note: Microdot may be in either location) *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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|------------------|---|--|-------------|--|
| DESCRIPTION: | SOT-223 (TO-261) | | PAGE 2 OF 2 | |
| | | | | |

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